

AMENDMENTS TO THE SPECIFICATION

Kindly replace the title of the invention with the following amended title:

METHOD FOR MANUFACTURING A SINGLE ELECTRON MEMORY DEVICE
COMPRISING HAVING QUANTUM DOTS BETWEEN GATE ELECTRODE AND SINGLE
ELECTRON STORAGE ELEMENT ~~AND METHOD FOR MANUFACTURING THE SAME~~

Kindly cancel the Abstract of the Disclosure and replace the Abstract of the Disclosure with a new Abstract of the Disclosure, which is attached at page 5 of this paper.